

VNS1NV04DTR-E

Data Sheet

Omnifet II: fully autoprotected Power MOSFET, MOSFET N-Ch 40V 1.7A Omni

Manufacturers STMicroelectronics, Inc.

Package/Case SO-8

Product Type Power Management ICs

RoHS Rohs



Images are for reference only

Lifecycle

Please submit RFQ for VNS1NV04DTR-E or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

VNS1NV04DTR-E is a specific part number for a power MOSFET transistor manufactured by STMicroelectronics. Here are some of its features:

Features Application

It is an N-channel MOSFET with a maximum drain-source voltage of 40V and a maximum continuous drain current of 1.2A. BSS138LT1G

It has a low on-resistance of 150mOhm at 4.5V gate-source voltage, which makes it suitable for low voltage applications. AO3400A

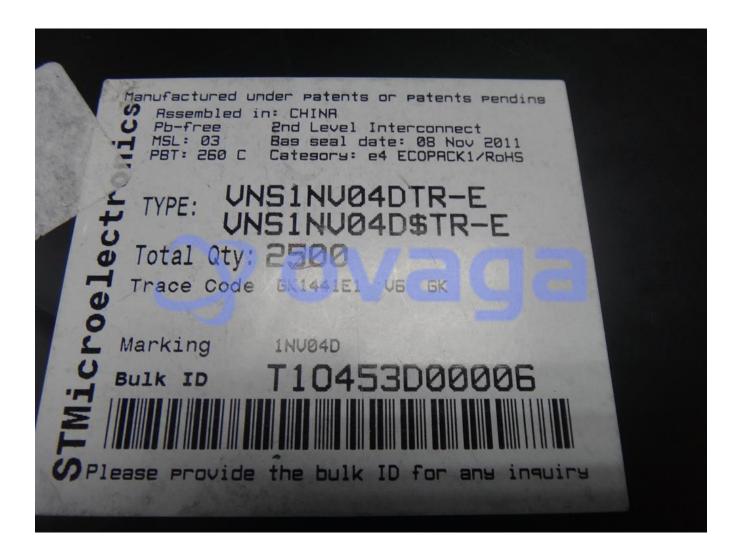
It is designed to be used in a wide range of applications, including DC-DC converters, battery chargers, power management, DMN3012LSS-13 and motor control.

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SI2319DS-T1-

GE3





Related Products



VN750PTTR-E

STMicroelectronics, Inc TO-252





VN750S-E

STMicroelectronics, Inc SOP-8



VN610SP

STMicroelectronics, Inc SOP-10



<u>VN808-E</u>

STMicroelectronics, Inc SOP36



VNB35NV04

STMicroelectronics, Inc D2PAK



VNQ5E250AJ-E

STMicroelectronics, Inc HSSOP-16



VN340SPTR-E

STMicroelectronics, Inc PowerSO-12



VND5N07-E

STMicroelectronics, Inc

TO-252